



# MT06N020A

## 主要参数 MAIN CHARACTERISTICS

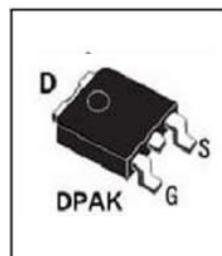
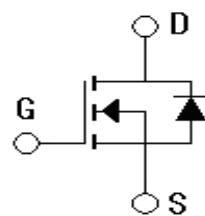
ID	50A
V <sub>DSS</sub>	60V
R <sub>dson-max</sub> (@V <sub>gs</sub> =10V)	18mΩ
Q <sub>g-typ</sub>	34nC

## 用途

- 高功率 DC/DC 转换与功率开关
- 直流电机控制
- 不间断电源
- High power DC/DC converters and switch mode power supplies
- DC motor control
- Uninterruptible power supply

## APPLICATIONS

## 封装 Package



## 产品特性

- 低栅极电荷
- 低 R<sub>dson</sub>
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品
- Low gate charge
- Low R<sub>dson</sub>
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

## FEATURES

## 订货信息 ORDER MESSAGE

订货型号 Order codes				印记 Marking	封装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
MT06N020A-R-B	MT06N020A-R-BR	MT06N020A-R-A	MT06N020A-R-AR	MT06N020A	DPAK



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绝对最大额定值 ABSOLUTE RATINGS (T<sub>c</sub>=25°C)

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
		MT06N020A	
最高漏极—源极直流电压 Drain-Source Voltage	V <sub>DSS</sub>	60	V
连续漏极电流 Drain Current -continuous	I <sub>D</sub> T=25°C	50*	A
	I <sub>D</sub> T=100°C	35*	A
最大脉冲漏极电流 (注 1) Drain Current - pulse (note 1)	I <sub>DM</sub>	200*	A
最高栅源电压 Gate-Source Voltage	V <sub>GSS</sub>	±20	V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	E <sub>AS</sub>	300	mJ
雪崩电流 Avalanche Current	I <sub>AS</sub>	35	A
耗散功率 Power Dissipation	P <sub>D</sub> T <sub>c</sub> =25°C	62.5	W
	-Derate above 25°C	0.5	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~+150	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T <sub>L</sub>	300	°C

\*漏极电流由最高结温限制

\*Drain current limited by maximum junction temperature



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## 电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最 小 Min	典 型 Typ	最 大 Max	单 位 Units
<b>关态特性 Off -Characteristics</b>						
漏—源击穿电压 Drain-Source Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	60	-	-	V
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V, T_C=25^\circ C$	-	-	1	$\mu A$
		$V_{DS}=48V, V_{GS}=0V, T_C=100^\circ C$	-	-	10	$\mu A$
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GSSF}$	$V_{DS}=0V, V_{GS} = 20V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GSSR}$	$V_{DS}=0V, V_{GS} = -20V$	-	-	-100	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D=30A$	-	15.0	18.0	$m\Omega$
<b>动态特性 Dynamic Characteristics</b>						
输入电容 Input capacitance	$C_{iss}$	$V_{DS}=30V, V_{GS} = 0V, f=1.0MHz$	-	1656	-	pF
输出电容 Output capacitance	$C_{oss}$		-	182	-	pF
反向传输电容 Reverse transfer capacitance	$C_{rss}$		-	97	-	pF



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## 电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics							
延迟时间 Turn-On delay time	t <sub>d(on)</sub>	V <sub>DD</sub> =30V, I <sub>D</sub> =30A, R <sub>G</sub> =3.0Ω (note 3, 4)	-	12.8	-	ns	
上升时间 Turn-On rise time	t <sub>r</sub>		-	61.6	-	ns	
延迟时间 Turn-Off delay time	t <sub>d(off)</sub>		-	26.4	-	ns	
下降时间 Turn-Off Fall time	t <sub>f</sub>		-	43.8	-	ns	
栅极电荷总量 Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =30V , I <sub>D</sub> =30A V <sub>GS</sub> =10V (note 3, 4)	-	34	-	nC	
栅一源电荷 Gate-Source charge	Q <sub>gs</sub>		-	12.3	-	nC	
栅一漏电荷 Gate-Drain charge	Q <sub>gd</sub>		-	10.3	-	nC	
漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings							
正向最大连续电流	I <sub>S</sub>		-	-	50	A	
Maximum Continuous Drain -Source Diode Forward Current	I <sub>SM</sub>		-	-	200	A	
正向最大脉冲电流	I <sub>SM</sub>		-	-	200	A	
正向压降	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =30A	-	-	1.3	V	
Drain-Source Diode Forward Voltage			-	-	1.3	V	
反向恢复时间	t <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =30A dI <sub>F</sub> /dt=100A/μs (note 3)	-	34.8	-	ns	
Reverse recovery charge	Q <sub>rr</sub>		-	40	-	nC	

## 热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最 大 Max		单 位 Unit
		MT06N020A		
结到管壳的热阻	R <sub>th(j-c)</sub>	2.0		°C/W
Thermal Resistance, Junction to Case				
结到环境的热阻	R <sub>th(j-A)</sub>	62.5		°C/W
Thermal Resistance, Junction to Ambient				

注释:

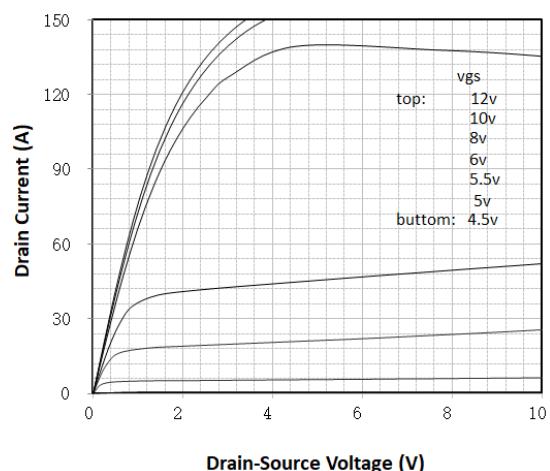
- 1: 脉冲宽度由最高结温限制  
 2: L=0.5mH, V<sub>DD</sub>=30V, R<sub>G</sub>=25 Ω, 起始结温  
     T<sub>J</sub>=25°C  
 3: 脉冲测试: 脉冲宽度≤300μs, 占空比≤2%  
 4: 基本与工作温度无关

Notes:

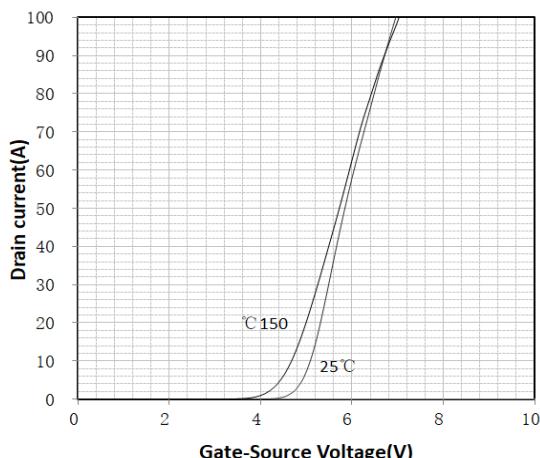
- 1: Pulse width limited by maximum junction temperature  
 2: L=0.5mH, V<sub>DD</sub>=30V, R<sub>G</sub>=25 Ω, Starting T<sub>J</sub>=25°C  
 3: Pulse Test: Pulse Width ≤300μs, Duty Cycle≤2%  
 4: Essentially independent of operating temperature

## 特征曲线 ELECTRICAL CHARACTERISTICS (curves)

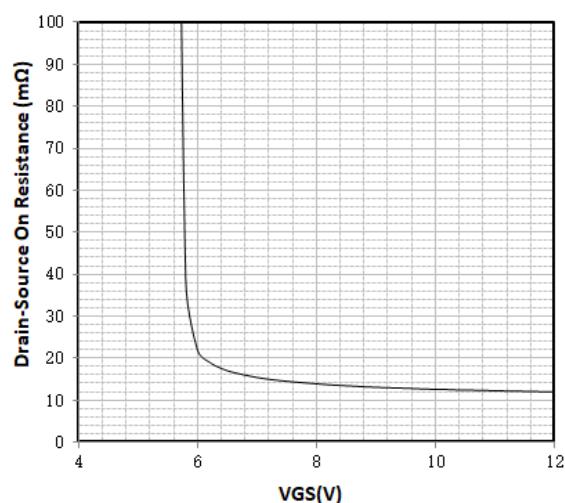
## On-Region Characteristics



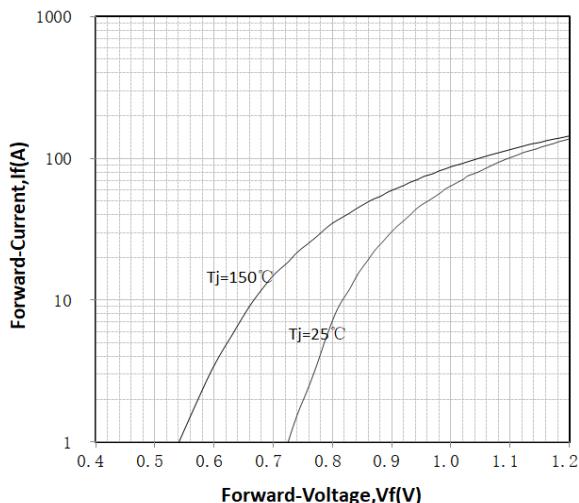
## Transfer Characteristics



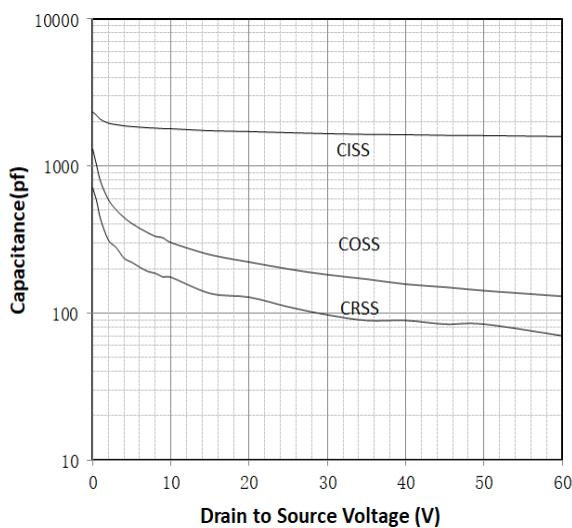
## On-Resistance Variation vs. Drain Current and Gate Voltage



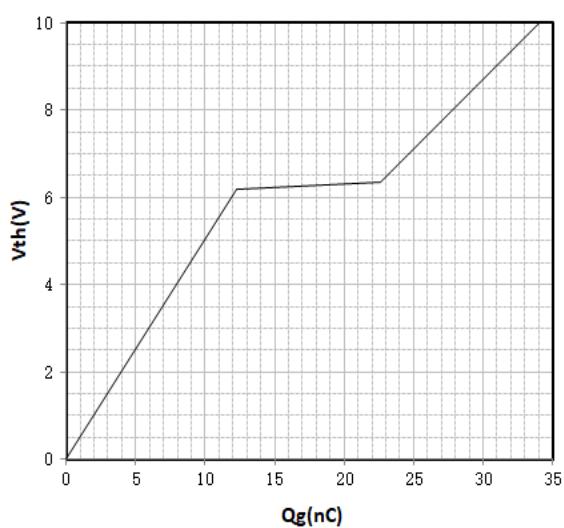
## Body Diode Forward Voltage Variation vs. Source Current and Temperature



## Capacitance Characteristics

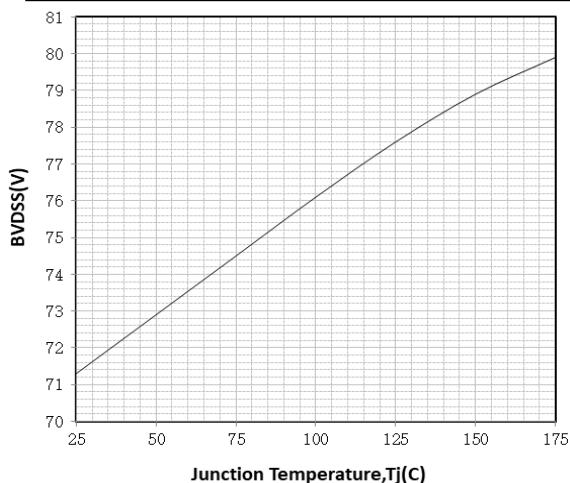


## Gate Charge Characteristics

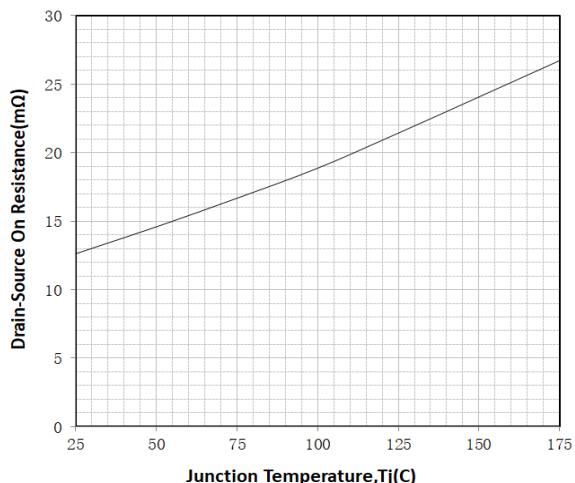


## 特征曲线 ELECTRICAL CHARACTERISTICS (curves)

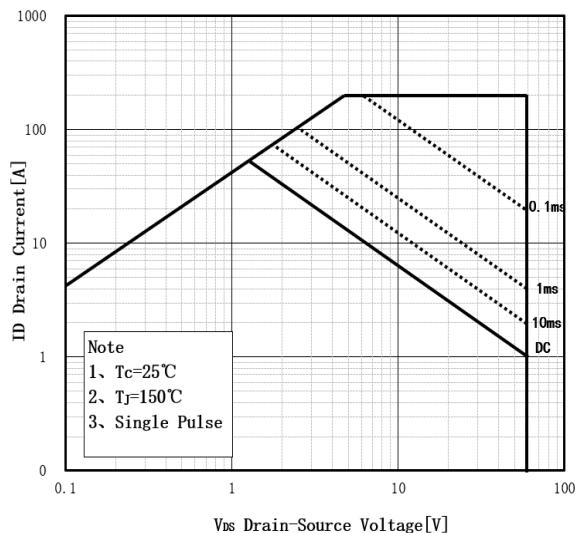
Breakdown Voltage Variation vs. Temperature



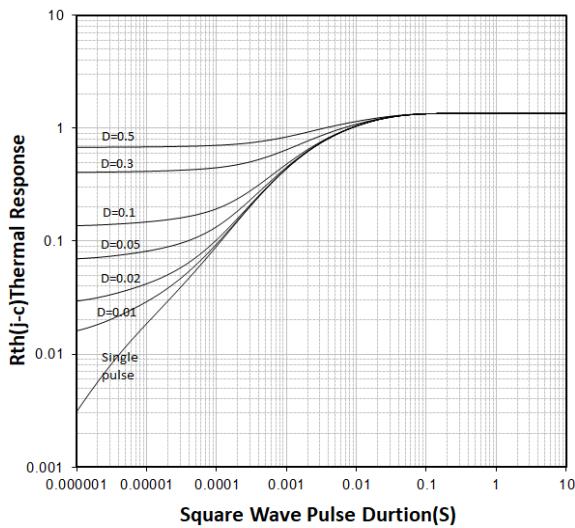
On-Resistance Variation vs. Temperature



Maximum Safe Operating Area



Transient Thermal Response Curve



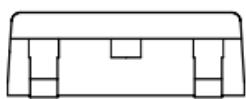
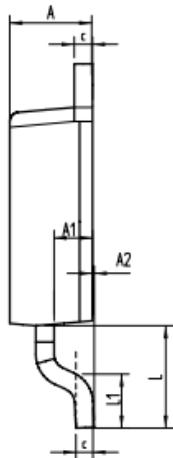
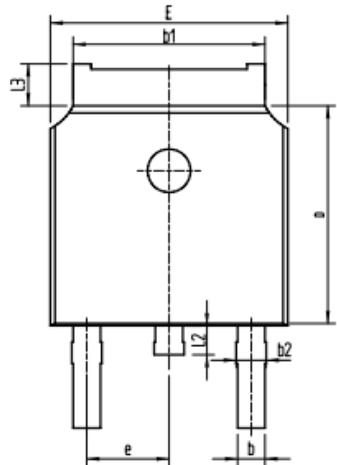


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## 外形尺寸 PACKAGE MECHANICAL DATA

DPAK

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30



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